

## Solid State Relay OCMOS FET PS7241-2B

## 8-PIN SOP, 400 V BREAK DOWN VOLTAGE NORMALLY CLOSE TYPE 2-ch Optical Coupled MOS FET

## DESCRIPTION

The PS7241-2B is a solid state relay containing GaAs LEDs on the light emitting side (input side) and normally close (N.C.) contact MOS FETs on the output side.

It is suitable for analog signal control because of their low offset and high linearity.

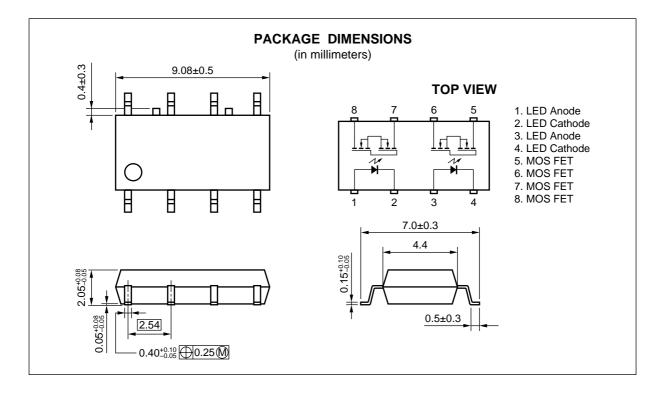
#### FEATURES

- 2 channel type (1 b + 1 b output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small and thin package (8-pin SOP, Height = 2.1 mm)
- Low offset voltage
- Ordering number of taping product: PS7241-2B-F3, F4
- UL approved: File No. E72422 (S)
- BSI approved: No. 8241/8242
- CSA approved: No. CA 101391

#### **APPLICATIONS**

- Exchange equipment
- Measurement equipment
- FA/OA equipment

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.



## **ORDERING INFORMATION (Solder Contains Lead)**

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7241-2B	8-pin SOP	Magazine case 45 pcs	PS7241-2B
PS7241-2B -F3		Embossed Tape 1 500 pcs/reel	
PS7241-2B -F4			

\*1 For the application of the Safety Standard, following part number should be used.

#### **ORDERING INFORMATION (Pb-Free)**

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7241-2B-A	8-pin SOP	Magazine case 45 pcs	PS7241-2B
PS7241-2B -F3-A		Embossed Tape 1 500 pcs/reel	
PS7241-2B -F4-A			

\*1 For the application of the Safety Standard, following part number should be used.

## ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	50	mA
	Reverse Voltage	VR	5	V
	Power Dissipation	PD	50	mW/ch
	Peak Forward Current *1	IFP	1	А
MOS FET	Break Down Voltage	VL	400	V
	Continuous Load Current	١L	120	mA
	Pulse Load Current <sup>*2</sup> (AC/DC Connection)	ILP	200	mA
	Power Dissipation	PD	180	mW/ch
Isolation Voltage *3		BV	1 500	Vr.m.s.
Total Power Dissipation		Рт	460	mW
Operating Ambient Temperature		TA	-40 to +85	°C
Storage Temperature		Tstg	-40 to +100	°C

 $\star$ 

\*1 PW = 100  $\mu$ s, Duty Cycle = 1 %

\*2 PW = 100 ms, 1 shot

\*3 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

## **RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)**

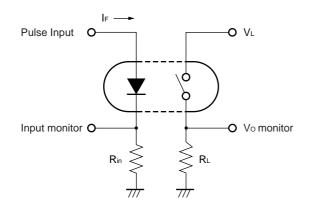
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lf	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

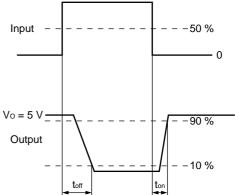
## ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	IR	V <sub>R</sub> = 5 V			5	μA
MOS FET	IOS FET Off-state Leakage Current		IF = 10 mA, VD = 400 V		0.03	1.0	μA
	Output Capacitance	Cout	IF = 10 mA, VD = 0 V, f = 1.0 MHz		185		pF/ch
Coupled	LED Off-state Current	Foff	I∟ = 120 mA			2.0	mA
	On-state Resistance	Ron1	IF = 0 mA, IL = 10 mA		21	30	Ω
		Ron2	$I_F = 0 \text{ mA}, I_L = 120 \text{ mA}, t \leq 10 \text{ ms}$		16	25	
	Turn-on Time <sup>*1</sup>	ton	IF = 10 mA, Vo = 5 V, RL = 500 Ω,		0.02	0.2	ms
	Turn-off Time *1	toff	PW ≥ 10 ms		0.1	1.0	
	Isolation Resistance	<b>R</b> ⊦o	VI-O = 1.0 kVDC	10 <sup>9</sup>			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1.0 MHz		0.4		pF/ch

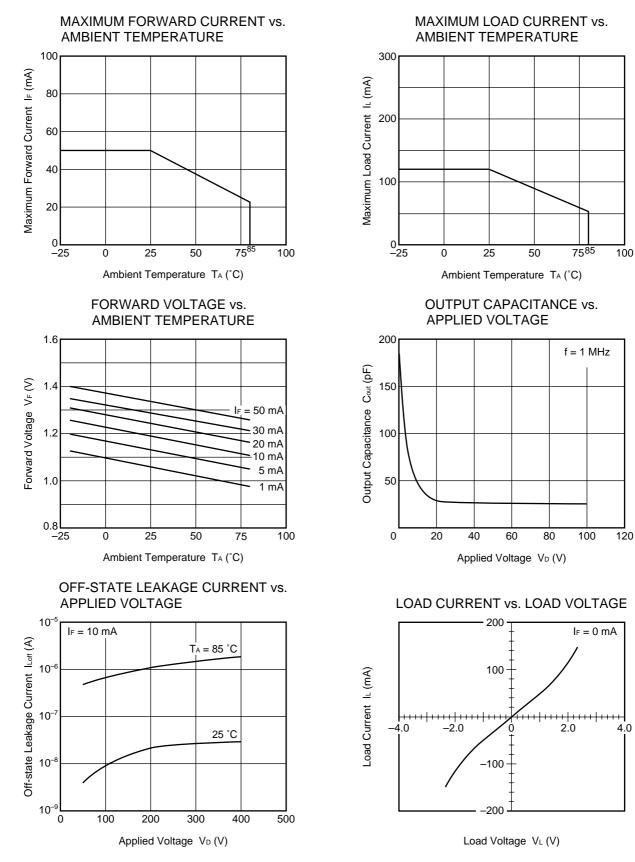
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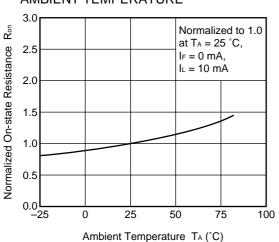
#### \*1 Test Circuit for Switching Time





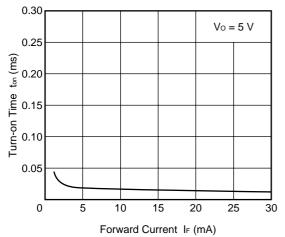
## ★ TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise specified)



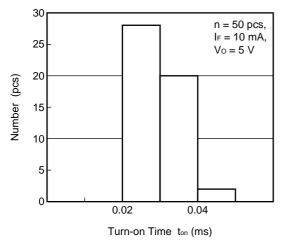


# NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE

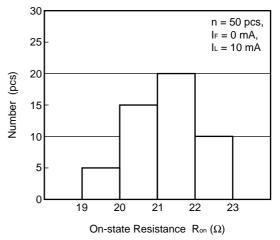




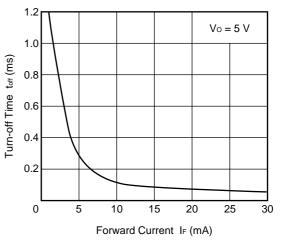
#### TURN-ON TIME DISTRIBUTION



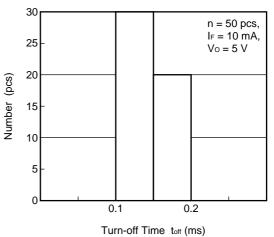
#### **ON-STATE RESISTANCE DISTRIBUTION**

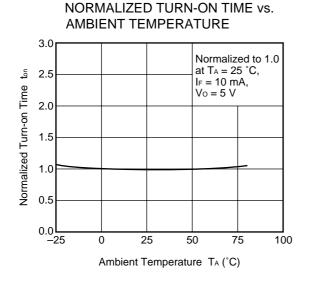


#### TURN-OFF TIME vs. FORWARD CURRENT

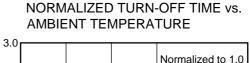


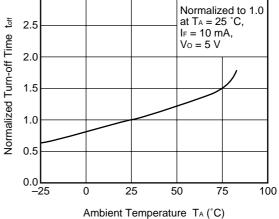
#### TURN-OFF TIME DISTRIBUTION



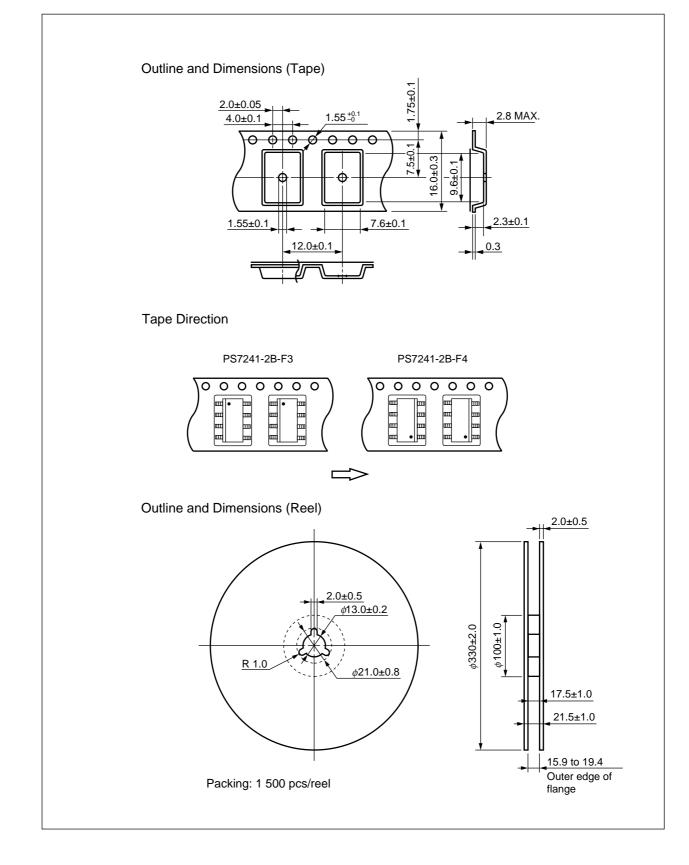


**Remark** The graphs indicate nominal characteristics.





## **★** TAPING SPECIFICATIONS (in millimeters)



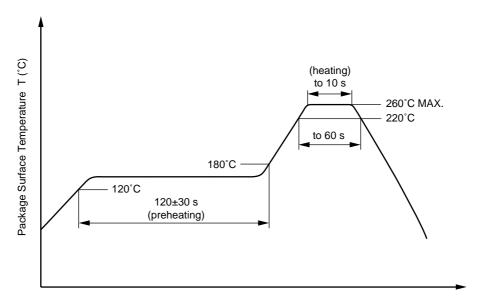
## ★ RECOMMENDED SOLDERING CONDITIONS

- (1) Infrared reflow soldering
  - Peak reflow temperature
  - Time of peak reflow temperature
  - Time of temperature higher than 220°C
  - Time to preheat temperature from 120 to  $180^\circ\text{C}$
  - Number of reflows
  - Flux

260°C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times
  One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.



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## Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
РВВ	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

# If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

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